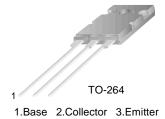


KSA1943

Audio Power Amplifier

- High Current Capability I_C = -13A
- High Power Dissipation
- Wide S.O.A
- Complement to KSC5200



PNP Epitaxial Silicon Transistor

Absolute Maximum Ratings T_C=25°C unless otherwise noted

| Symbol | Parameter | Ratings | Units |
|------------------|--|------------|-------|
| V_{CBO} | Collector-Base Voltage | -230 | V |
| V _{CEO} | Collector-Emitter Voltage | -230 | V |
| V _{EBO} | Emitter-Base Voltage | -5 | V |
| I _C | Collector Current | -13 | Α |
| I _B | Base Current | -1.5 | Α |
| P _C | Collector Dissipation (T _C =25°C) | 130 | W |
| T _J | Junction Temperature | 150 | °C |
| T _{STG} | Storage Temperature | - 50 ~ 150 | °C |

Electrical Characteristics T_C=25°C unless otherwise noted

| Symbol | Parameter | Test Condition | Min. | Тур. | Max. | Units |
|-----------------------|--------------------------------------|--|------|------|------|-------|
| BV _{CBO} | Collector-Base Breakdown Voltage | I_C =-5mA, I_E =0 | -230 | | | V |
| BV _{CEO} | Collector-Emitter Breakdown Voltage | I _C =-10mA, R _{BE} =∞ | -230 | | | V |
| BV _{EBO} | Emitter-Base Breakdown Voltage | I_E =-5mA, I_C =0 | -5 | | | V |
| I _{CBO} | Collector Cut-off Current | V_{CB} =-230V, I_{E} =0 | | | -5.0 | μΑ |
| I _{EBO} | Emitter Cut-off Current | V_{EB} =-5V, I_{C} =0 | | | -5.0 | μΑ |
| h _{FE1} | * DC Current Gain | V _{CE} =-5V, I _C =-1A | 55 | | 160 | |
| h _{FE2} | DC Current Gain | V _{CE} =-5V, I _C =-7A | 35 | 60 | | |
| V _{CE} (sat) | Collector-Emitter Saturation Voltage | I _C =-8A, I _B =-0.8A | | -0.4 | -3.0 | V |
| V _{BE} (on) | Base-Emitter ON Voltage | V _{CE} =-5V, I _C =-7A | | -1.0 | -1.5 | V |
| f _T | Current Gain Bandwidth Product | V _{CE} =-5V, I _C =-1A | | 30 | | MHz |
| C _{ob} | Output Capacitance | V _{CB} =-10V, f=1MHz | | 360 | | pF |

^{*} Pulse Test : PW=20us

*h_{FE} Classification

| Classification | R | 0 |
|------------------|----------|----------|
| h _{FE1} | 55 ~ 110 | 80 ~ 160 |

Typical Characteristics

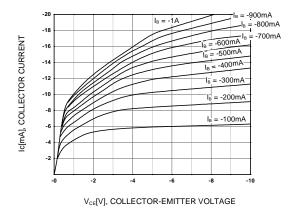


Figure 1. Static Characteristic

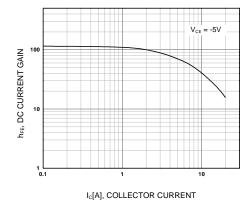


Figure 2. DC current Gain

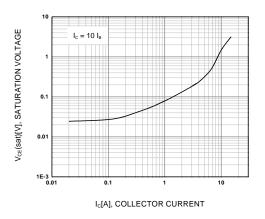


Figure 3. Collector-Emitter Saturation Voltage

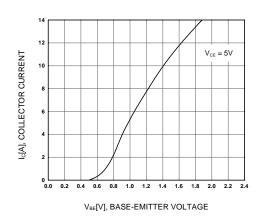


Figure 4. Collector-Emitter Saturation Voltage

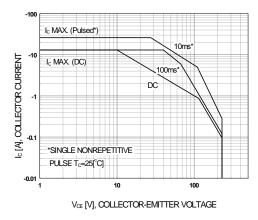


Figure 5. Safe Operating Area

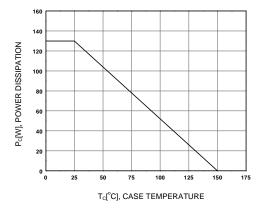
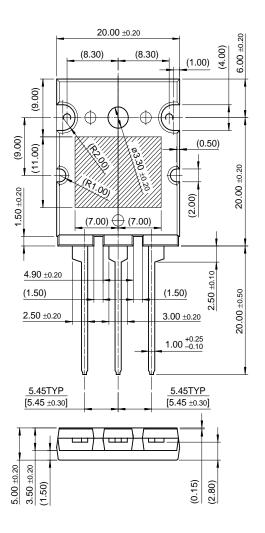


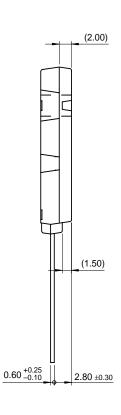
Figure 6. Power Derating

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Package Demensions

TO-264





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